

SILICON DRIFT DETECTORS CGX-103

SDD in place of Si-Pin Detector for enhanced performance & Detection (Spectral Resolution)



All specifications are same except the sensor which is Silicon Drift Detector

Specifications :

Detectable elements
Measurement Results

: Titanium to Uranium
: Iron (Fe), Cobalt (Co), Nickel (Ni), Copper (Cu), Zinc (Zn), Ruthenium (Ru), Rhodium (Rh), Palladium (Pd), Silver (Ag), Cadmium (Cd), Indium (In), Tin (Sn), Osmium (Os), Iridium (Ir), Platinum (Pt), Gold (Au)
-all metals separately.

Accuracy of measurement

: The accuracy of measurement is better than Silicon-Pin Detector

Sensor

: Silicon Drift Detector is used in place of Silicon-Pin Diode Detector for enhanced performance & spectral resolutions.

Cooling for Detector

: Thermoelectric

Detection Range

: 0.1%-----99.99%

Testing Time

: 30-----200 secs

Test Spot Area

: 0.5mm

Power Supply

: 90-240 V AC, 50/60HZ

Power Rating

: 30 Watt

Working Temperature

: 15-25°C

Relative humidity

: <70%

Operation atmosphere

: Vibration free surface and air conditioned room

Interface for Computer

: Inbuilt (External Computer required)

Software for Operation

: Menu Driven User Friendly Operating System

Dimensions of Instrument

: Length : 335mm
Width : 225mm
Height : 210mm (with test compartment cover in closed position) & 330mm (in open position).

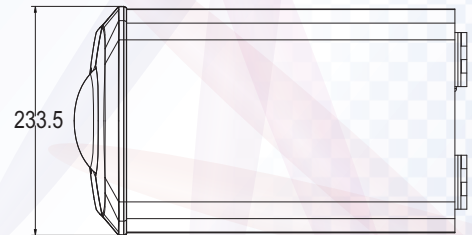
Dimensions of Sample Chamber : Length : 235mm

Width : 195mm

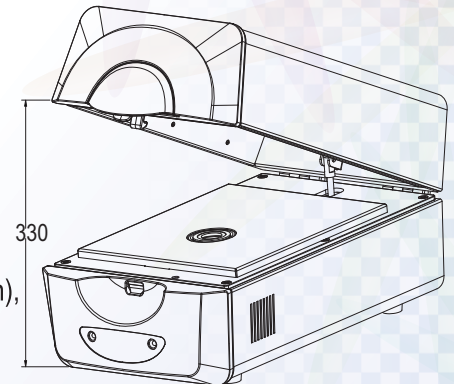
Height : 80mm

Net Weight

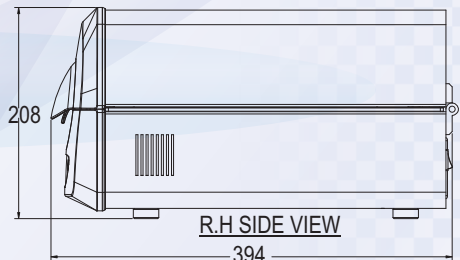
: 12kg



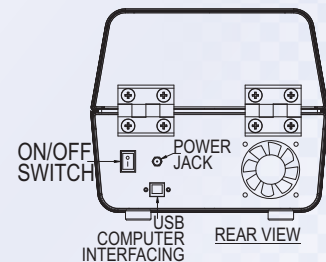
TOP VIEW



FRONT VIEW



R.H SIDE VIEW



REAR VIEW

